NSN 5961-01-269-0928

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-269-0928 **Inclosure Material:** Plastic **Overall Length:** 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** 0.205 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.8 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 1500.0 watts small-signal input power, common-emitter megahertz **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0